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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Attorney Docket Number

29137.051.00 US

U.S. PATENT DOCUMENTS

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**Examiner
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/Marie R. Yamnitzky/ (01/12/2009)

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Application Number	10/722,812
		Filing Date	November 26, 2003
		First Named Inventor	SON, Se Hwan
		Art Unit	4774 1794
		Examiner Name	M.R. Yamnitzky
		Attorney Docket Number	29137.051.00 US
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FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document Country Code ³ -Number ⁴ - Kind Code ⁵ (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
/MRY/		JP 07-11249 A	01/13/1995	Mitsui Petrochem Ind Ltd	English Abstract	■
/MRY/		JP 2005-167175	06/2003 2005	Novaled GMBH	English Abstract	■
/MRY/		JP-06-163158 A	06/10/1994	Pioneer Elec. Co.	English Abstract	■
/MRY/		KR-10-2000-0082085 20010062711	12/26/2000	LG Chem Investments, Ltd.	English Abstract	■
/MRY/		KR 10-2003/0067773 A	08/19/2003	LG Chemical Ltd.		■
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/MRY/		WO 03/012890 A2	02/2003	Technische Universitat		

NON PATENT LITERATURE DOCUMENTS						
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.				T ²
/MRY/		Kim, J.S. et al., "Indium-tin oxide treatment for single- and double-layer polymeric light-emitting diodes: The relation between the anode physical, chemical, and morphological properties and the device performance", Journ. of Applied Physics, Vol. 84, No. 12, pp. 6859-70 (Dec. 1998).				
/MRY/		Kruger, Jessica et al., "Modification of TiO ₂ Heterojunctions with Benzoic Acid Derivatives in Hybrid Molecular Solid-State Devices," Advanced Materials, Vol. 12, pp. 447-51 (2000).				
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/MRY/		G. Gu, et al., "Transparent Organic Light Emitting Devices", Applied Physics Letters, vol. 68 (19), p. 2606-2608 (May 1996).				
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/MRY/		J. Cui et al., "Indium Tin Oxide Alternatives - High Work Function Transparent Conducting Oxides As Anodes For Organic Light-Emitting Diodes", pp. 1476-1480, Advanced Materials, 2001, 13, No. 19, (Oct. 2001).				

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. ¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the application number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

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* previously made of record